CMOS Digital Integrated Circuits Silicon Monolithic

# TC7WZ86FU

#### 1. Functional Description

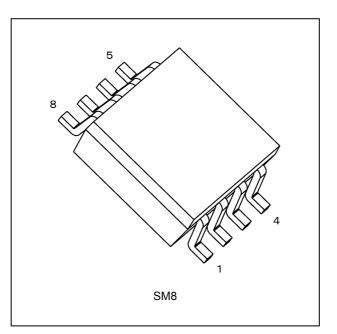
• Dual Exclusive-OR Gate

#### 2. Features

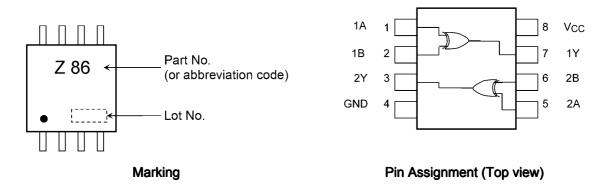
- (1) Wide operating temperature range:  $T_{opr} = -40$  to 125 °C (Note 1)
- (2) High output current:  $\pm 24$  mA (min) at V<sub>CC</sub> = 3.0 V
- (3) Super high speed operation:  $t_{pd} = 2.9$  ns (typ.) at  $V_{CC} = 5.0$  V,  $C_L = 50$  pF
- (4) Operation voltage range:  $V_{CC} = 1.65$  to 5.5 V
- (5) 5.5 V tolerant inputs
- (6) 5.5 V power down protection output
- (7) Matches the performance of TC74LCX series when operated at  $3.3 \text{ V} V_{CC}$

Note 1: For devices with the ordering part number ending in  $J(CT. T_{opr} = -40$  to 85 °C for the other devices.

#### 3. Packaging

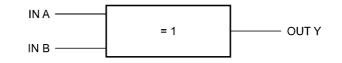


4. Marking and Pin Assignment



Start of commercial production 2020-01 2020-02-04 Rev.4.0

### 5. IEC Logic Symbol



#### 6. Truth Table

| А | В | Y |
|---|---|---|
| L | L | L |
| L | Н | Н |
| Н | L | Н |
| Н | Н | L |

### 7. Absolute Maximum Ratings (Note) (Unless otherwise specified, Ta = 25 °C)

| Characteristics                 | Symbol           | Note     | Rating                        | Unit |
|---------------------------------|------------------|----------|-------------------------------|------|
| Supply voltage                  | V <sub>CC</sub>  |          | -0.5 to 6.0                   | V    |
| Input voltage                   | V <sub>IN</sub>  |          | -0.5 to 6.0                   | V    |
| DC output voltage               | V <sub>OUT</sub> | (Note 1) | -0.5 to 6.0                   | V    |
|                                 |                  | (Note 2) | -0.5 to V <sub>CC</sub> + 0.5 |      |
| Input diode current             | I <sub>IK</sub>  |          | -20                           | mA   |
| Output diode current            | Ι <sub>ΟΚ</sub>  | (Note 3) | -20                           | mA   |
| DC output current               | I <sub>OUT</sub> |          | ±50                           | mA   |
| V <sub>CC</sub> /ground current | I <sub>CC</sub>  |          | ±50                           | mA   |
| Power dissipation               | PD               |          | 300                           | mW   |
| Storage temperature             | T <sub>stg</sub> |          | -65 to 150                    | °C   |

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1:  $V_{CC}$  = 0 V

Note 2: High (H) or Low (L) state. I<sub>OUT</sub> absolute maximum rating must be observed.

Note 3: V<sub>OUT</sub> < GND

### 8. Operating Ranges (Note)

| Characteristics          | Symbol           | Note     | Test Condition                       | Rating               | Unit |
|--------------------------|------------------|----------|--------------------------------------|----------------------|------|
| Supply voltage           | V <sub>CC</sub>  |          | —                                    | 1.65 to 5.5          | V    |
|                          |                  | (Note 1) | —                                    | 1.5 to 5.5           |      |
| Input voltage            | V <sub>IN</sub>  |          | —                                    | 0 to 5.5             | V    |
| Output voltage           | V <sub>OUT</sub> | (Note 2) | —                                    | 0 to 5.5             | V    |
|                          |                  | (Note 3) | —                                    | 0 to V <sub>CC</sub> |      |
| Operating temperature    | T <sub>opr</sub> | (Note 4) | —                                    | -40 to 125           | 0°   |
|                          |                  | (Note 5) | —                                    | -40 to 85            |      |
| Input rise and fall time | dt/dv            |          | $V_{CC}$ = 1.8 ± 0.15 V, 2.5 ± 0.2 V | 0 to 20              | ns/V |
|                          |                  |          | $V_{CC}$ = 3.3 ± 0.3 V               | 0 to 10              |      |
|                          |                  |          | $V_{CC}$ = 5.0 ± 0.5 V               | 0 to 5               |      |

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either  $V_{CC}$  or GND.

Note 1: Data retention only

Note 2: V<sub>CC</sub> = 0 V

Note 3: High (H) or Low (L) state.

Note 4: For devices with the ordering part number ending in J(CT.

Note 5: For devices except those with the ordering part number ending in J(CT.

#### 9. Electrical Characteristics

#### 9.1. DC Characteristics (Unless otherwise specified, $T_a = 25$ °C)

| Characteristics              | Symbol           | Test Condition                                       | I  | V <sub>CC</sub> (V) | Min                 | Тур. | Max                  | Unit |
|------------------------------|------------------|--|--|---------------------|---------------------|------|----------------------|------|
| High-level input voltage     | V <sub>IH</sub>  | _  |  | 1.65 to<br>1.95     | $V_{CC} 	imes 0.75$ | —    | —                    | V    |
|                              |                  |  |  | 2.3 to 5.5          | $V_{CC} 	imes 0.70$ | _    | _                    |      |
| Low-level input voltage      | V <sub>IL</sub>  | _  |  | 1.65 to<br>1.95     | _                   | —    | $V_{CC} 	imes 0.25$  | V    |
|                              |                  |  |  | 2.3 to 5.5          | —                   | _    | $V_{CC} \times 0.30$ |      |
| High-level output voltage    | V <sub>OH</sub>  | $V_{IN} = V_{IH} \text{ or } V_{IL}$                 | I <sub>OH</sub> = -100 μA                    | 1.65                | 1.55                | 1.65 | —                    | V    |
|                              |                  |  |  | 2.3                 | 2.2                 | 2.3  | —                    |      |
|                              |                  |  |  | 3.0                 | 2.9                 | 3.0  | _                    |      |
|                              |                  |  |  | 4.5                 | 4.4                 | 4.5  | _                    |      |
|                              |                  |  | I <sub>OH</sub> = -4 mA                      | 1.65                | 1.29                | 1.52 | _                    |      |
|                              |                  |  | I <sub>OH</sub> = -8 mA                      | 2.3                 | 1.9                 | 2.15 | _                    |      |
|                              |                  |  | I <sub>OH</sub> = -16 mA                     | 3.0                 | 2.4                 | 2.8  | _                    |      |
|                              |                  |  | I <sub>OH</sub> = -24 mA                     | 3.0                 | 2.3                 | 2.68 | _                    |      |
|                              |                  |  | I <sub>OH</sub> = -32 mA                     | 4.5                 | 3.8                 | 4.2  | _                    |      |
| Low-level output voltage     | V <sub>OL</sub>  | V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> | I <sub>OL</sub> = 100 μA                     | 1.65                | _                   | 0.0  | 0.1                  | V    |
|                              |                  |  |  | 2.3                 | _                   | 0.0  | 0.1                  |      |
|                              |                  |  |  | 3.0                 | _                   | 0.0  | 0.1                  |      |
|                              |                  |  |  | 4.5                 | _                   | 0.0  | 0.1                  |      |
|                              |                  |  | I <sub>OL</sub> = 4 mA                       | 1.65                | _                   | 0.08 | 0.24                 |      |
|                              |                  |  | I <sub>OL</sub> = 8 mA                       | 2.3                 | _                   | 0.1  | 0.3                  |      |
|                              |                  |  | I <sub>OL</sub> = 16 mA                      | 3.0                 | _                   | 0.15 | 0.4                  |      |
|                              |                  |  | I <sub>OL</sub> = 24 mA                      | 3.0                 | _                   | 0.22 | 0.55                 |      |
|                              |                  |  | I <sub>OL</sub> = 32 mA                      | 4.5                 | _                   | 0.22 | 0.55                 |      |
| Input leakage current        | I <sub>IN</sub>  | V <sub>IN</sub> = 5.5 V or GND                       |  | 0 to 5.5            | _                   | _    | ±1                   | μA   |
| Power-OFF leakage<br>current | I <sub>OFF</sub> | V <sub>IN</sub> or V <sub>OUT</sub> = 5.5 V          | $V_{IN} \text{ or } V_{OUT} = 5.5 \text{ V}$ |                     | —                   | _    | 1                    | μA   |
| Quiescent supply current     | I <sub>CC</sub>  | V <sub>IN</sub> = 5.5 V or GND                       |  | 1.65 to 5.5         | _                   |      | 1                    | μA   |

#### 9.2. DC Characteristics (Unless otherwise specified, T<sub>a</sub> = -40 to 85 °C)

| Characteristics           | Symbol           | Test Conditio                        | Test Condition            |              | Min                  | Max                  | Unit |
|---------------------------|------------------|--------------------------------------|---------------------------|--------------|----------------------|----------------------|------|
| High-level input voltage  | V <sub>IH</sub>  | _                                    |                           | 1.65 to 1.95 | $V_{CC} 	imes 0.75$  | —                    | V    |
|                           |                  |                                      |                           | 2.3 to 5.5   | $V_{CC} \times 0.70$ | _                    |      |
| Low-level input voltage   | VIL              | _                                    |                           | 1.65 to 1.95 | _                    | $V_{CC} 	imes 0.25$  | V    |
|                           |                  |                                      |                           | 2.3 to 5.5   | _                    | $V_{CC} \times 0.30$ |      |
| High-level output voltage | V <sub>OH</sub>  | $V_{IN} = V_{IH} \text{ or } V_{IL}$ | I <sub>OH</sub> = -100 μA | 1.65         | 1.55                 | —                    | V    |
|                           |                  |                                      |                           | 2.3          | 2.2                  | —                    |      |
|                           |                  |                                      |                           | 3.0          | 2.9                  | _                    |      |
|                           |                  |                                      |                           | 4.5          | 4.4                  | _                    |      |
|                           |                  |                                      | I <sub>OH</sub> = -4 mA   | 1.65         | 1.29                 | _                    |      |
|                           |                  |                                      | I <sub>OH</sub> = -8 mA   | 2.3          | 1.9                  | _                    |      |
|                           |                  |                                      | I <sub>OH</sub> = -16 mA  | 3.0          | 2.4                  | —                    |      |
|                           |                  |                                      | I <sub>OH</sub> = -24 mA  | 3.0          | 2.3                  | _                    |      |
|                           |                  |                                      | I <sub>OH</sub> = -32 mA  | 4.5          | 3.8                  | _                    |      |
| Low-level output voltage  | V <sub>OL</sub>  | $V_{IN} = V_{IH} \text{ or } V_{IL}$ | I <sub>OL</sub> = 100 μA  | 1.65         | —                    | 0.1                  | V    |
|                           |                  |                                      |                           | 2.3          | _                    | 0.1                  |      |
|                           |                  |                                      |                           | 3.0          | —                    | 0.1                  |      |
|                           |                  |                                      |                           | 4.5          | —                    | 0.1                  |      |
|                           |                  |                                      | I <sub>OL</sub> = 4 mA    | 1.65         | —                    | 0.24                 |      |
|                           |                  |                                      | I <sub>OL</sub> = 8 mA    | 2.3          | —                    | 0.3                  |      |
|                           |                  |                                      | I <sub>OL</sub> = 16 mA   | 3.0          | —                    | 0.4                  |      |
|                           |                  |                                      | I <sub>OL</sub> = 24 mA   | 3.0          | —                    | 0.55                 |      |
|                           |                  |                                      | I <sub>OL</sub> = 32 mA   | 4.5          | —                    | 0.55                 |      |
| Input leakage current     | I <sub>IN</sub>  | V <sub>IN</sub> = 5.5 V or GND       |                           | 0 to 5.5     | —                    | ±10                  | μA   |
| Power-OFF leakage current | I <sub>OFF</sub> | $V_{IN}$ or $V_{OUT}$ = 5.5 V        |                           | 0            | —                    | 10                   | μA   |
| Quiescent supply current  | I <sub>CC</sub>  | V <sub>IN</sub> = 5.5 V or GND       |                           | 1.65 to 5.5  | _                    | 10                   | μA   |

### 9.3. DC Characteristics (Note) (Unless otherwise specified, $T_a = -40$ to 125 °C)

| Characteristics           | Symbol           | Test Condition                                       |                           | V <sub>CC</sub> (V) | Min                  | Max                  | Unit |
|---------------------------|------------------|--|---------------------------|---------------------|----------------------|----------------------|------|
| High-level input voltage  | VIH              | _  |                           | 1.65 to 1.95        | $V_{CC} 	imes 0.75$  | —                    | V    |
|                           |                  |  |                           | 2.3 to 5.5          | $V_{CC} \times 0.70$ | _                    |      |
| Low-level input voltage   | V <sub>IL</sub>  | _  |                           | 1.65 to 1.95        | _                    | $V_{CC} 	imes 0.25$  | V    |
|                           |                  |  |                           | 2.3 to 5.5          | _                    | $V_{CC} \times 0.30$ |      |
| High-level output voltage | V <sub>OH</sub>  | $V_{IN} = V_{IH} \text{ or } V_{IL}$                 | I <sub>OH</sub> = -100 μA | 1.65                | 1.55                 | _                    | V    |
|                           |                  |  |                           | 2.3                 | 2.2                  | _                    |      |
|                           |                  |  |                           | 3.0                 | 2.9                  | _                    |      |
|                           |                  |  |                           | 4.5                 | 4.4                  | _                    |      |
|                           |                  |  | I <sub>OH</sub> = -4 mA   | 1.65                | 0.95                 | _                    |      |
|                           |                  |  | I <sub>OH</sub> = -8 mA   | 2.3                 | 1.7                  | _                    |      |
|                           |                  |  | I <sub>OH</sub> = -16 mA  | 3.0                 | 2.2                  | _                    |      |
|                           |                  |  | I <sub>OH</sub> = -24 mA  | 3.0                 | 2.0                  | _                    |      |
|                           |                  |  | I <sub>OH</sub> = -32 mA  | 4.5                 | 3.4                  | _                    |      |
| Low-level output voltage  | V <sub>OL</sub>  | V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> | I <sub>OL</sub> = 100 μA  | 1.65                | _                    | 0.1                  | V    |
|                           |                  |  |                           | 2.3                 | _                    | 0.1                  |      |
|                           |                  |  |                           | 3.0                 | _                    | 0.1                  |      |
|                           |                  |  |                           | 4.5                 | _                    | 0.1                  |      |
|                           |                  |  | I <sub>OL</sub> = 4 mA    | 1.65                | _                    | 0.7                  |      |
|                           |                  |  | I <sub>OL</sub> = 8 mA    | 2.3                 | _                    | 0.45                 |      |
|                           |                  |  | I <sub>OL</sub> = 16 mA   | 3.0                 | _                    | 0.6                  |      |
|                           |                  |  | I <sub>OL</sub> = 24 mA   | 3.0                 | _                    | 0.8                  |      |
|                           |                  |  | I <sub>OL</sub> = 32 mA   | 4.5                 | _                    | 0.8                  |      |
| Input leakage current     | I <sub>IN</sub>  | V <sub>IN</sub> = 5.5 V or GND                       | •                         | 0 to 5.5            | —                    | ±20                  | μA   |
| Power-OFF leakage current | I <sub>OFF</sub> | V <sub>IN</sub> or V <sub>OUT</sub> = 5.5 V          |                           | 0                   | _                    | 100                  | μA   |
| Quiescent supply current  | I <sub>CC</sub>  | V <sub>IN</sub> = 5.5 V or GND                       |                           | 1.65 to 5.5         | _                    | 100                  | μA   |

Note: For devices with the ordering part number ending in J(CT.

#### 9.4. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

| Characteristics        | Symbol                             | Note     | Test<br>Condition      | V <sub>CC</sub> (V)              | C <sub>L</sub> (pF) | Min | Тур. | Max  | Unit |
|------------------------|------------------------------------|----------|------------------------|----------------------------------|---------------------|-----|------|------|------|
| Propagation delay time | t <sub>PLH</sub> ,t <sub>PHL</sub> |          | $R_L = 1 M\Omega$      | $\textbf{1.8} \pm \textbf{0.15}$ | 15                  | 2.0 | 4.9  | 11.5 | ns   |
|                        |                                    |          |                        | $\textbf{2.5}\pm\textbf{0.2}$    |                     | 0.8 | 3.8  | 8.0  |      |
|                        |                                    |          |                        | $\textbf{3.3}\pm\textbf{0.3}$    |                     | 0.5 | 3.0  | 5.7  |      |
|                        |                                    |          |                        | $5.0\pm0.5$                      |                     | 0.5 | 2.4  | 5.0  |      |
|                        |                                    |          | R <sub>L</sub> = 500 Ω | $\textbf{3.3}\pm\textbf{0.3}$    | 50                  | 1.5 | 3.5  | 6.2  | ns   |
|                        |                                    |          |                        | $5.0\pm0.5$                      |                     | 0.8 | 2.9  | 5.4  |      |
| Input capacitance      | C <sub>IN</sub>                    |          | —                      | 0 to 5.5                         | _                   | _   | 3    | _    | pF   |
| Power dissipation      | C <sub>PD</sub>                    | (Note 1) | —                      | 3.3                              | _                   | _   | 22   | _    | pF   |
| capacitance            |                                    |          |                        | 5.5                              |                     | _   | 32   | _    |      |

Note 1:  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.  $I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2 \text{ (per 1 gate)}$ 

### 9.5. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 3$ ns)

| Characteristics        | Symbol                             | Test Condition         | V <sub>CC</sub> (V)           | C <sub>L</sub> (pF) | Min | Max  | Unit |
|------------------------|------------------------------------|------------------------|-------------------------------|---------------------|-----|------|------|
| Propagation delay time | t <sub>PLH</sub> ,t <sub>PHL</sub> | $R_L = 1 M\Omega$      | $1.8\pm0.15$                  | 15                  | 2.0 | 12.0 | ns   |
|                        |                                    |                        | $2.5\pm0.2$                   |                     | 0.8 | 8.5  |      |
|                        |                                    |                        | $\textbf{3.3}\pm\textbf{0.3}$ |                     | 0.5 | 6.0  |      |
|                        |                                    |                        | $5.0\pm0.5$                   |                     | 0.5 | 5.4  |      |
|                        |                                    | R <sub>L</sub> = 500 Ω | $\textbf{3.3}\pm\textbf{0.3}$ | 50                  | 1.5 | 6.5  | ns   |
|                        |                                    |                        | $5.0\pm0.5$                   |                     | 0.8 | 5.8  |      |

#### 9.6. AC Characteristics (Note) (Unless otherwise specified, T<sub>a</sub> = -40 to 125 °C, Input: t<sub>r</sub> = t<sub>f</sub> = 3 ns)

| Characteristics        | Symbol                             | Test Condition         | V <sub>CC</sub> (V)           | C <sub>L</sub> (pF) | Min | Max  | Unit |
|------------------------|------------------------------------|------------------------|-------------------------------|---------------------|-----|------|------|
| Propagation delay time | t <sub>PLH</sub> ,t <sub>PHL</sub> | $R_L = 1 M\Omega$      | $1.8\pm0.15$                  | 15                  | 2.0 | 13.5 | ns   |
|                        |                                    |                        | $2.5\pm0.2$                   |                     | 0.8 | 9.5  |      |
|                        |                                    |                        | $3.3\pm0.3$                   |                     | 0.5 | 7.0  |      |
|                        |                                    |                        | $5.0\pm0.5$                   |                     | 0.5 | 6.0  |      |
|                        |                                    | R <sub>L</sub> = 500 Ω | $\textbf{3.3}\pm\textbf{0.3}$ | 50                  | 1.5 | 7.5  | ns   |
|                        |                                    |                        | $5.0\pm0.5$                   |                     | 0.8 | 6.5  |      |

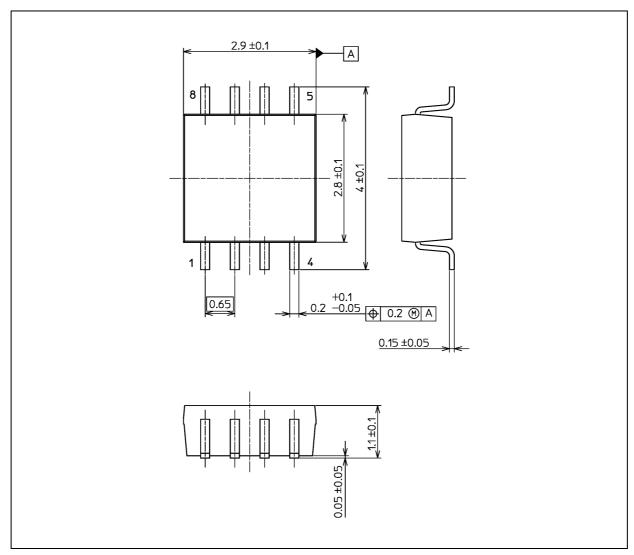
Note: For devices with the ordering part number ending in J(CT.



### TC7WZ86FU

#### **Package Dimensions**

Unit: mm



Weight: 21 mg (typ.)

|                | Package Name(s) |
|----------------|-----------------|
| JEDEC: SOT-505 |                 |
| Nickname: SM8  |                 |

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